



**CHENMKO ENTERPRISE CO.,LTD**

Halogens free devices

**SURFACE MOUNT**

**NPN Digital Silicon Transistor**

**VOLTAGE 50 Volts CURRENT 100 mAmpere**

**CHUMH3GP**

#### APPLICATION

- \* Switching circuit, Inverter, Interface circuit, Driver circuit.

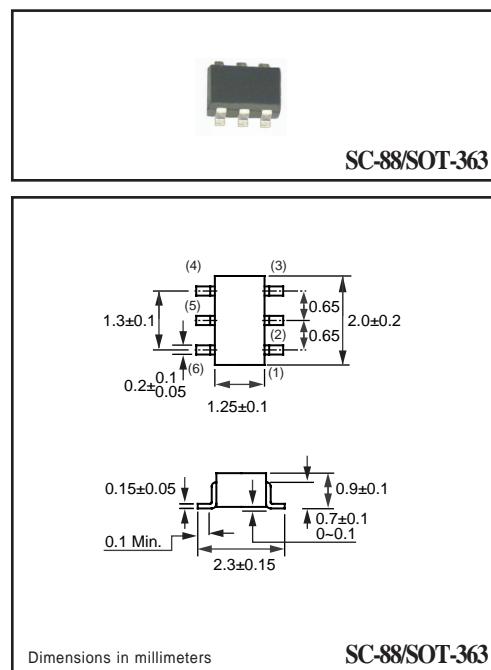
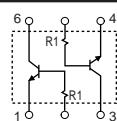
#### FEATURE

- \* Small surface mounting type. (SC-88/SOT-363)
- \* High current gain.
- \* Suitable for high packing density.
- \* Low collector-emitter saturation.
- \* High saturation current capability.
- \* Two CHDTC143T chips in one package.
- \* Built in bias resistor( $R_1=4.7\text{k}\Omega$ , Typ. )



**SC-88/SOT-363**

#### CIRCUIT



**SC-88/SOT-363**

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$V_{CBO}$	Collector-Base voltage		50	V
$V_{CEO}$	Collector-Emitter voltage		50	V
$V_{EBO}$	Emitter-Base voltage		5	V
$I_C(\text{Max.})$	Collector current		100	mA
$P_D$	Power dissipation	$T_{\text{amb}} \leq 25^\circ\text{C}$ , Note 1	150	mW
$T_{STG}$	Storage temperature		-55 +150	°C
$T_J$	Junction temperature		150	°C

#### Note

- Transistor mounted on an FR4 printed-circuit board.

## RATING CHARACTERISTIC ( CHUMH3GP )

### CHARACTERISTICS

$T_{amb} = 25^{\circ}\text{C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
BVCBO	Collector-Base breakdown voltage	$I_c=50\mu\text{A}$	50.0	—	—	V
BVCEO	Collector-Emitter breakdown voltage	$I_c=1\text{mA}$	50.0	—	—	V
BVEBO	Emitter-Base breakdown voltage	$I_e=50\mu\text{A}$	5.0	—	—	V
VCE(sat)	Collector-Emitter Saturation voltage	$I_c=5\text{mA}; I_b=0.25\text{mA}$	—	—	0.3	V
$I_{CBO}$	Collector-Base current	$V_{CB}=50\text{V}$	—	—	0.5	$\mu\text{A}$
$I_{EBO}$	Emitter-Base current	$V_{EB}=4\text{V}$	—	—	0.5	$\mu\text{A}$
$h_{FE}$	DC current gain	$I_c=1\text{mA}; V_{CE}=5.0\text{V}$	100	250	600	
$R_1$	Input resistor		3.29	4.7	6.11	$\text{k}\Omega$
$f_T$	Transition frequency	$I_e=-5\text{mA}, V_{CE}=10.0\text{V}$ $f=100\text{MHz}$	—	250	—	MHz

### Note

1. Pulse test:  $t_p \leq 300\mu\text{s}$ ;  $\delta \leq 0.02$ .

## RATING CHARACTERISTIC CURVES ( CHUMH3GP )

### Typical Electrical Characteristics

Fig.1 DC current gain vs. collector current

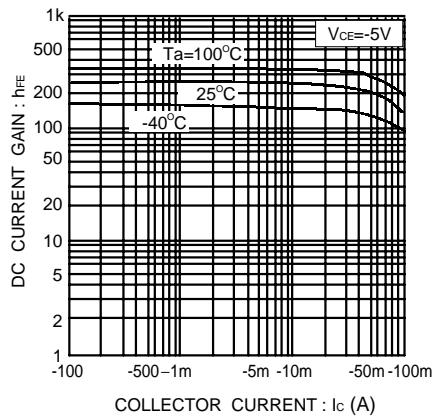


Fig.2 Collector-emitter saturation voltage vs. collector current

